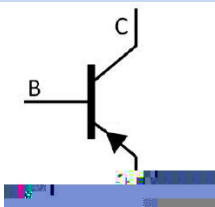


Silicon PNP transistor in a SOT-23 Plastic Package.

Excellent h_{FE} linearity, complementary pair with KTC3876.

General amplifier and switching application.



PIN 1 Base PIN 2 Emitter PIN 3 Collector

h_{FE} Classifications Symbol	O	Y	GR
h_{FE} Range	70 140	120 240	200 400
Marking	HAZO	HAZY	HAZG

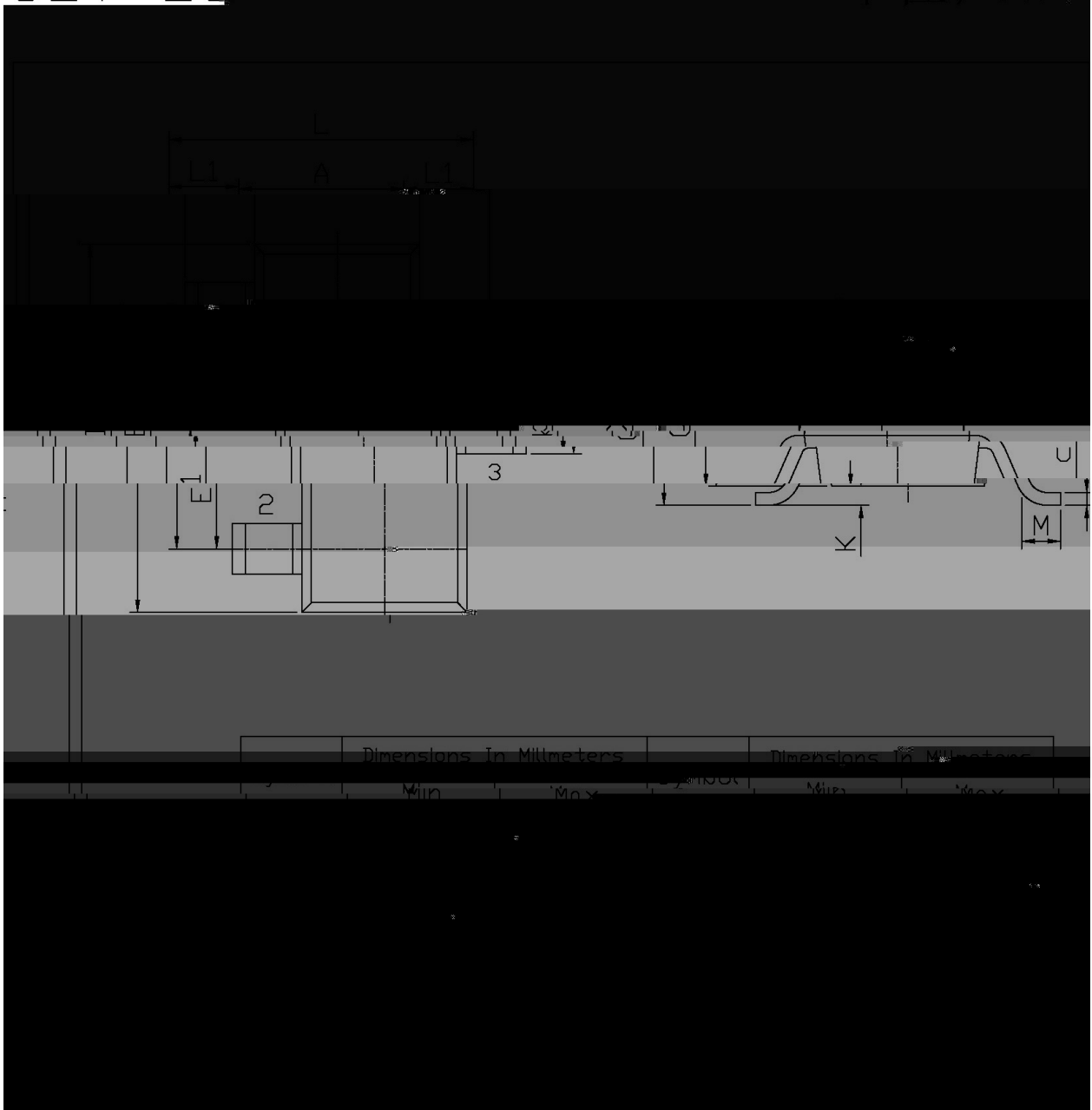
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-35	V
Collector to Emitter Voltage	V_{CEO}	-30	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current	I_C	-500	mA
Base Current	I_B	-50	mA
Collector Power Dissipation	P_C	150	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cut-Off Current	I_{CBO}	$V_{CB}=-35V$ $I_E=0$			-0.1	μA
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=-5.0V$ $I_C=0$			-0.1	μA
DC Current Gain	$h_{FE(1)}$	$V_{CE}=-1.0V$ $I_C=-100mA$	70		400	
	$h_{FE(2)}$	$V_{CE}=-6.0V$ $I_C=-400mA$	25			
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-100mA$ $I_B=-10mA$		-0.1	-0.25	V
Base-Emitter Voltage	V_{BE}	$V_{CE}=-1.0V$ $I_C=-100mA$		-0.8	-1.0	V
Transition Frequency	f_T	$V_{CE}=-6.0V$ $I_C=-20mA$		200		MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=-6.0V$ $I_E=0$ $f=1.0MHz$		13		pF



SOT-23

单位:  





Note:

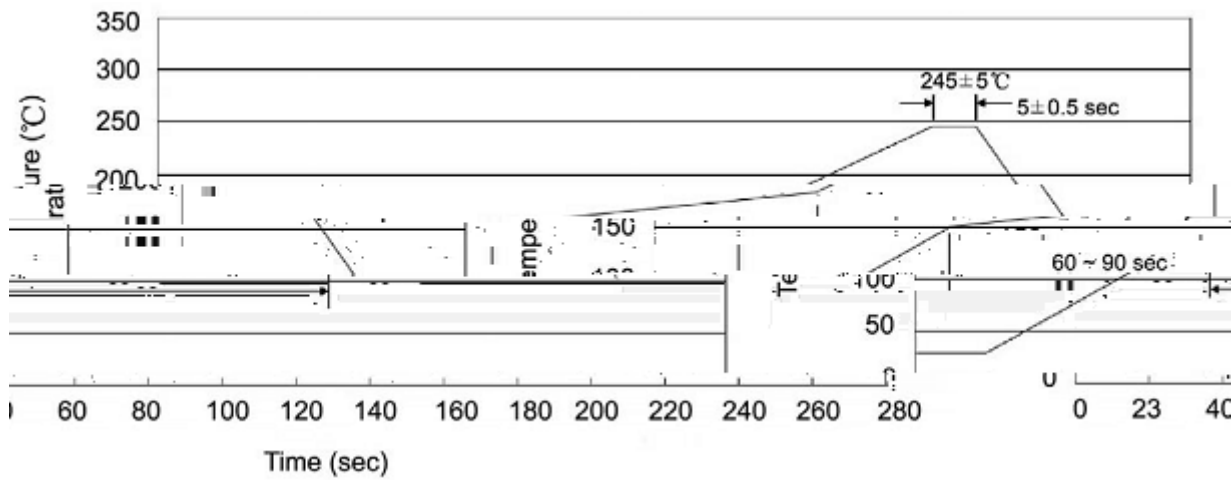
Company Code

AZ

Product Type

h_{FE} Classifications Symbol

Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

- 1

25 150

60 90sec;

1.Preheating:25~150 , Time:60~90sec.
- 2

245 5

5 0.5sec;

2.Peak Temp.:245 5 , Duration:5 0.5sec.
- 3

2 10 /sec.

3. Cooling Speed: 2~10 /sec.

260 5

10 1 sec.

Temp.:260 5

Time:10 1 sec

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	只 卷盘	卷盘 盒	只 盒	盒 箱	只 箱		盒	箱